Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.200 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.210 inches and 0.225 inches
Function For Which Designed:
Switching
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.0 reverse gate to source voltage and 500.0 forward voltage, peak and 150.0 reverse voltage, peak
Current Rating Per Characteristic:
30.00 amperes source cutoff current outside diameter and 25.00 milliamperes emitter current, dc megawatts
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0